What is claimed is: 1. A push-pull driver circuit, comprising: an NMOS output transistor and PMOS output transistor connected between a voltage source and ground, wherein the respective drains of the NMOS and PMOS output transistors are commonly connected to a driver circuit output terminal; an NMOS pre-driver transistor driving the NMOS output transistor in response to a transmit signal being applied to the NMOS pre-driver transistor through a drive signal path; a non-overlap circuit defining a non-overlap signal path for the transmit signal being applied to the NMOS pre-driver transistor; and wherein the delay through the non-overlap signal path is less than the delay through the drive signal path. 2. The push-pull driver circuit of claim 1, further comprising: a boot-strap circuit defining a boot-strap signal path for the transmit signal being applied to the NMOS pre-driver transistor, wherein the delay through the boot-strap path is greater than the delay through the non-overlap signal path and less than the delay through the drive signal path. 3. The push-pull driver of claim 2, wherein the boot-strap circuit comprises: a gate detecting an output voltage at the driver circuit output terminal and generating a charge pump enable signal; a charge pump circuit applying charge to the NMOS pre-driver transistor in response to the charge pump enable signal.

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feedback loop.

- 5. The push-pull driver of claim 1, further comprising:
- a circuit for disabling the PMOS output transistor.

4. The push-pull driver of claim 3, wherein the charge pump circuit comprises a positive

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6. A circuit comprising:

a push-pull output driver having an output driver current path comprising a NMOS drive transistor and a PMOS drive transistor connected between a voltage source and ground, and also having an output driver reference element;

a process detector having a process detector reference element and providing at least one control signal defining a switching signal for the push-pull output driver;

a feedback circuit indicating current shoot-through occurring in the push-pull output driver and providing a feedback control signal; and,

a control circuit receiving the at least one control signal and modifying the switching signal in response to the feedback control signal;

wherein the output driver reference element and the process detector element respond similarly to variations in fabrication processes for the circuit, as well as operating temperature and operating voltage.

- 7. The circuit of claim 6, wherein the process detector comprises a delay lock loop (DLL) and the at least one control signal comprises digital codes derived from the DLL.
 - 8. The circuit of claim 7 further comprising:

an adjustment circuit receiving the digital control codes;

separate P and N data registers respectively storing P control codes and N control codes;

a first digital to analog (D/A) converter receiving the P control codes and generating an analog P bias signal;

a second D/A converter receiving the N control codes and generating an analog N bias signal; and,

a pre-driver circuit comprising a NMOS pre-driver transistor receiving the N bias signal and a CMOS pre-driver transistor receiving the P bias signal.

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9. The circuit of claim 7, wherein the feedback circuit comprises:

a mirrored output driver current path comprising a NMOS mirror transistor and a PMOS mirror transistor;

resistors converting a current output from the NMOS mirror transistor into an N feedback voltage and a current output from the PMOS mirror transistor into a P feedback voltage;

a XOR gate receiving the N feedback voltage and the P feedback voltage and generating a shoot-through flag when shoot-through is indicated in the mirrored output driver current path.

10. The circuit of claim 9, wherein the control circuit comprises:

latch circuits capturing shoot-through flags from the XOR gate and providing a pumpup signal to control logic storing a copy of the digital control codes;

wherein the control logic defining a shoot-through detection cycle and resetting the latch circuits following each shoot-through detection cycle.

11. A method of defining performance in a push-pull driver circuit having an output driver current path comprising a first output transistor and a second output transistor connected between a voltage source and ground, the method comprising:

defining a transmission switching signal for the first and second output transistors; detecting shoot-through in the output driver current path;

generating a feedback signal in response to a detection of shoot-through in the output driver current path; and,

modifying the transmission switching signal in response to the feedback signal.

- 12. The method of claim 11, wherein the transmission switching signal comprises a first switching signal applied to the first output transistor and a second switching signal applied to the second output transistor.
- 13. The method of claim 12, wherein the step of modifying the transmission switching signal comprises adjusting the duty cycle of at least one of the first and second switching signals.

- 14. The method of claim 12, wherein the step of modifying the transmission switching signal comprises adjusting modifying a delay between the first and second switching signals.
- 15. The method of claim 1, wherein the push-pull driver further comprises a driver mirror current path arranged in parallel with the output driver current path, the driver mirror current path comprising a first mirror transistor sized in relation to the first output transistor and a second mirror transistor sized in relation to the second output transistor, and wherein the step of detecting shoot-through in the output driver current path comprises:

detecting mirrored shoot-though current in the driver mirror current path.

16. The method of claim 15, further comprising:

converting the mirrored shoot-though current into a shoot-through detection voltage, wherein the feedback signal is derived from the shoot-through detection voltage.

17. The method of claim 16, wherein the step of defining a transmission switching signal for the first and second output transistors comprises; defining control codes in a process detector having at least one process detector reference element, wherein the control codes determine the transmission switching signal for the first and second output transistors;

wherein the step of modifying the transmission switching signal in response to the feedback signal comprises; incrementing the control codes in response to the feedback signal; and

wherein at least one of the first and second output transistors comprises an output driver reference element that tracks performance of the process detector element over a range of variations in fabrication process, operating temperature, and operating voltage.

1	18. An output driver circuit, comprising:
2	a PMOS output transistor having a source connected to a voltage source and a drain
3	connected to an output terminal;
4	a NMOS output transistor having source connected to ground and a drain connected to
5	the output terminal;
6	a pre-driver circuit operable in one of two modes, the first mode applying a transmit
7	signal to the PMOS output transistor and the NMOS output transistor to form a push-pull output
8	driver circuit, and the second mode applying the transmit signal to only the NMOS output
9	transistor to form an open-gate NMOS driver circuit.
1	19. The output driver of claim 18, further comprising:
2	a boot-strap circuit increasing enhancing the rising edge of an output signal in both the
<u>F</u> 3	first and second modes; and
	a non-overlap circuit being enabled in the first mode and disabled in the second mode.
14 14	20. A method of defining performance in a push-pull driver comprising a first output
2	transistor and a second output transistor and an output driver current path between the first and
	second output transistors, the method comprising:
	defining digital control codes in relation to a process detector, wherein the process
	detector exhibits performance characteristics which track the performance characteristics of the
16	first and second output transistors;
7	defining a transmission switching signal for at least one of the first and second output
8	transistors in relation to the digital control codes;
9	detecting shoot-through in the output driver current path;
10	generating a feedback signal in response to a detection of shoot-through in the driver
11	current path;
12	modifying the digital control codes in response to the feedback signal.

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- 21. The method of claim 20, wherein the process detector comprises a Delay Lock Loop circuit having performance characteristics that track the performance characteristics of the first and second output transistors in relation to at least one of process, voltage, and temperature.
- 22. A method of controlling shoot-through current in a push-pull driver circuit, comprising:

defining a transmission switching signal for the push-pull driver circuit in relation to a control signal received from a process detector;

adjusting the control signal and thereby modifying the transmission switching signal until a shoot-through crossover point is determined at which no shoot-through current occurs in the push-pull driver circuit;

upon determining the shoot-through crossover point, periodically dithering the control signal to re-introduce shoot-through current;

following re-introduction of shoot-through current, adjusting the control signal and thereby modifying the transmission switching signal until a new shoot-through crossover point is determined at which no shoot-through current occurs in the push-pull driver circuit.